

The intense positron source EPOS at Research Center Rossendorf

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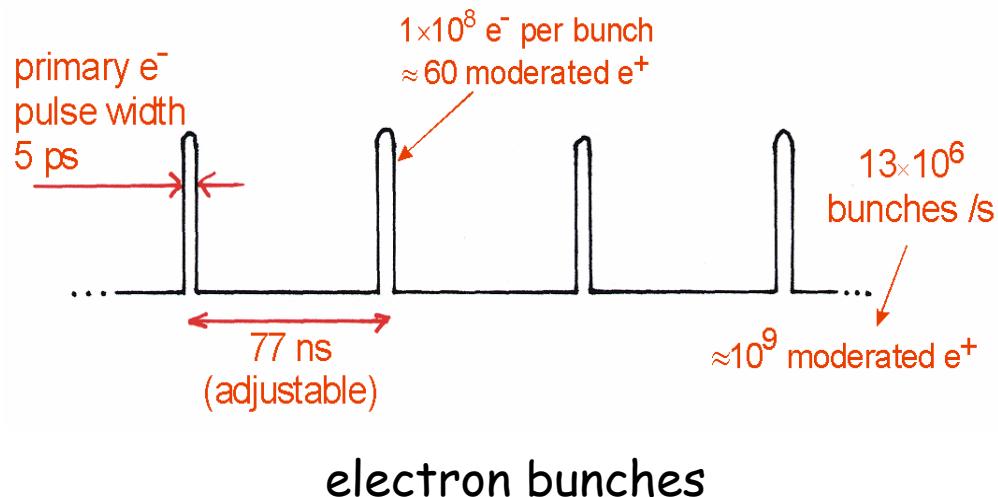
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²FZ Rossendorf



The EPOS positron source at Research Center Rossendorf

- Main experiment in Rossendorf: Radiation source ELBE = Electron Linac with high Brilliance and low Emittance
- Primary electron beam ($40 \text{ MeV} \times 1 \text{ mA} = 40 \text{ kW}$)
- Main goal: IR Free-electron Laser
- Very interesting time structure: cw-mode of short bunches

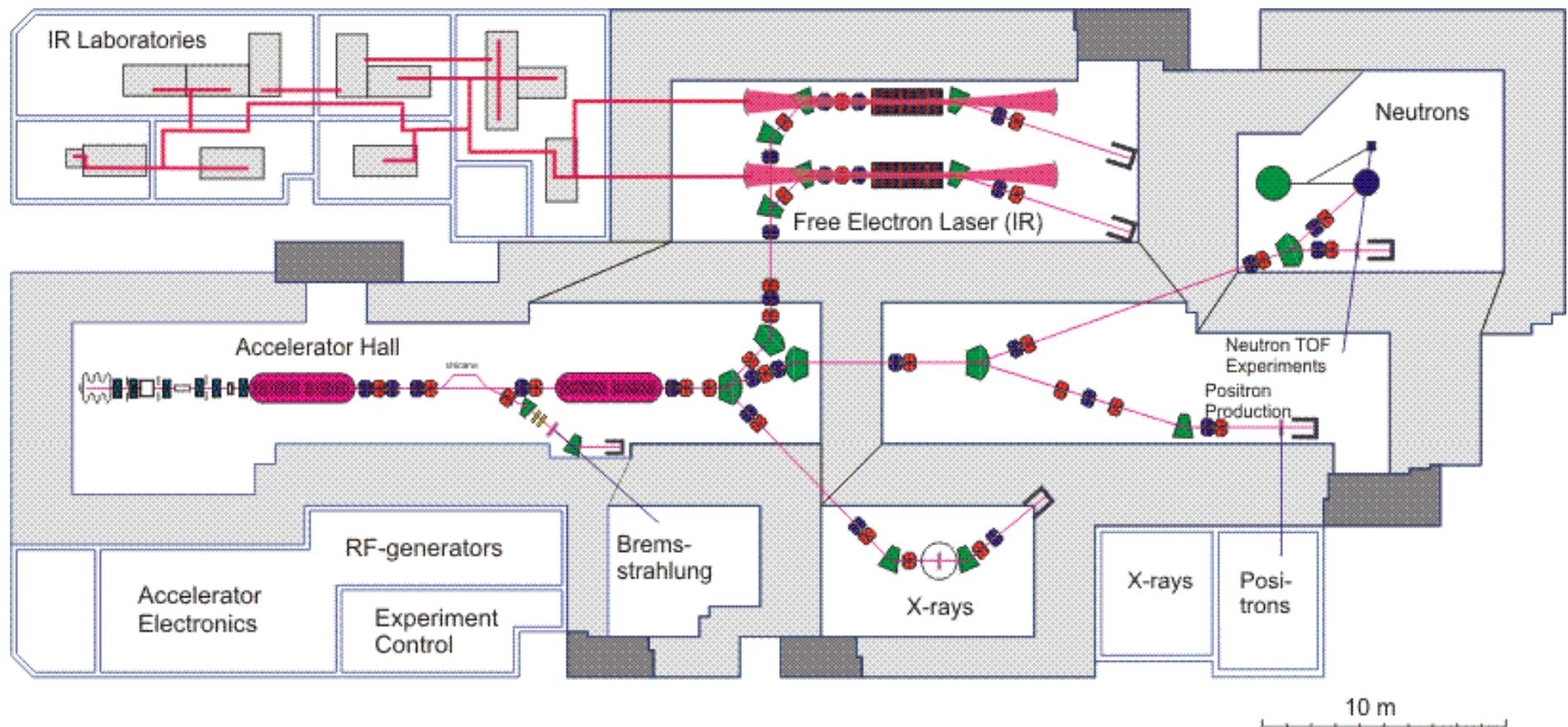


EPOS = ELBE Positron Source

- Intense beam of slow (monoenergetic) positrons
- All relevant positron techniques for materials research (positron lifetime, Coincidence Doppler broadening, AMOC)
- EPOS is external facility of Martin-Luther-University Halle at Research center Rossendorf
- User-dedicated facility
- Remote controlled via internet
- Financing by University Halle, Land Sachsen-Anhalt and European Community



Ground map of the ELBE hall



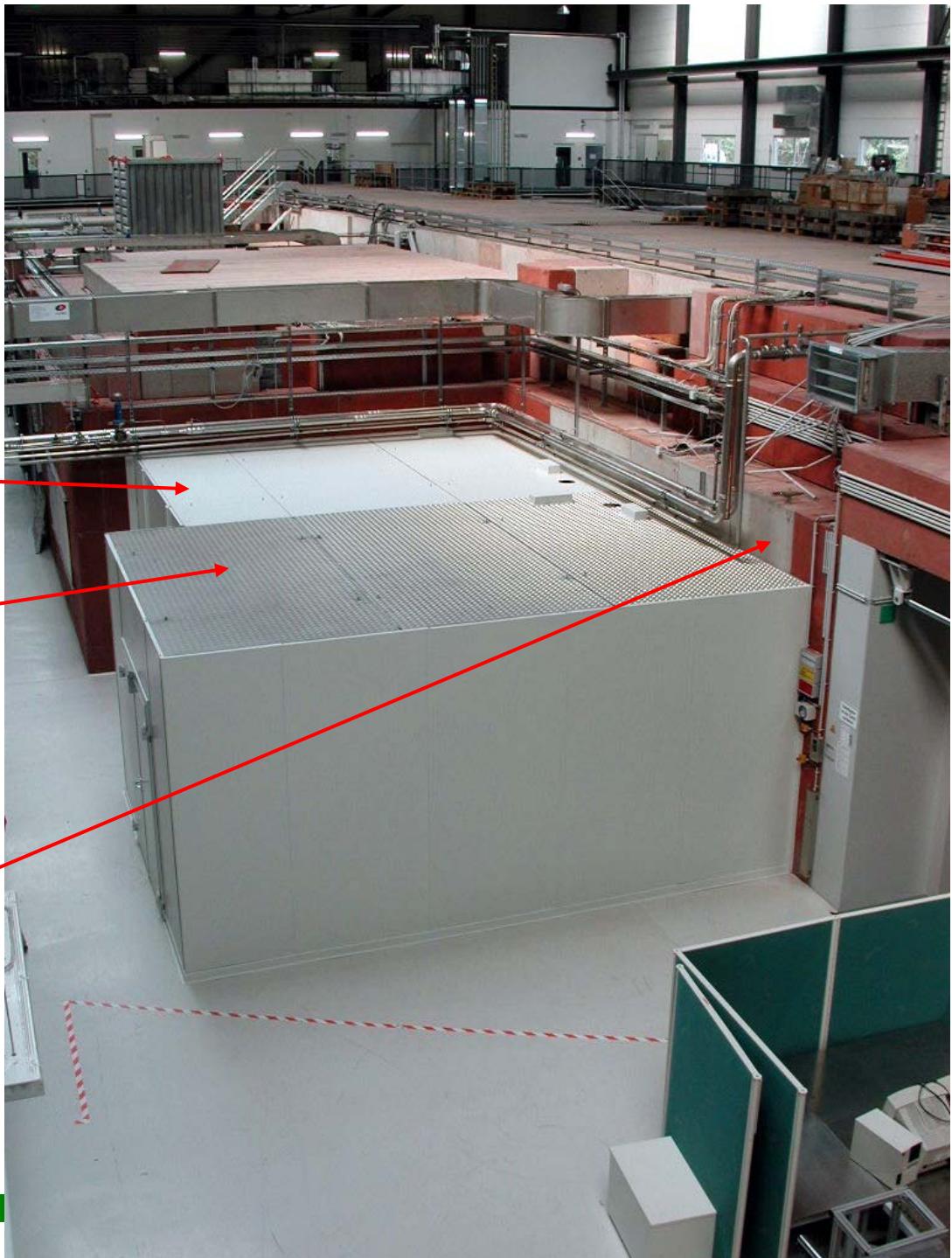
Positron Lab

- positron lab in ELBE hall already available

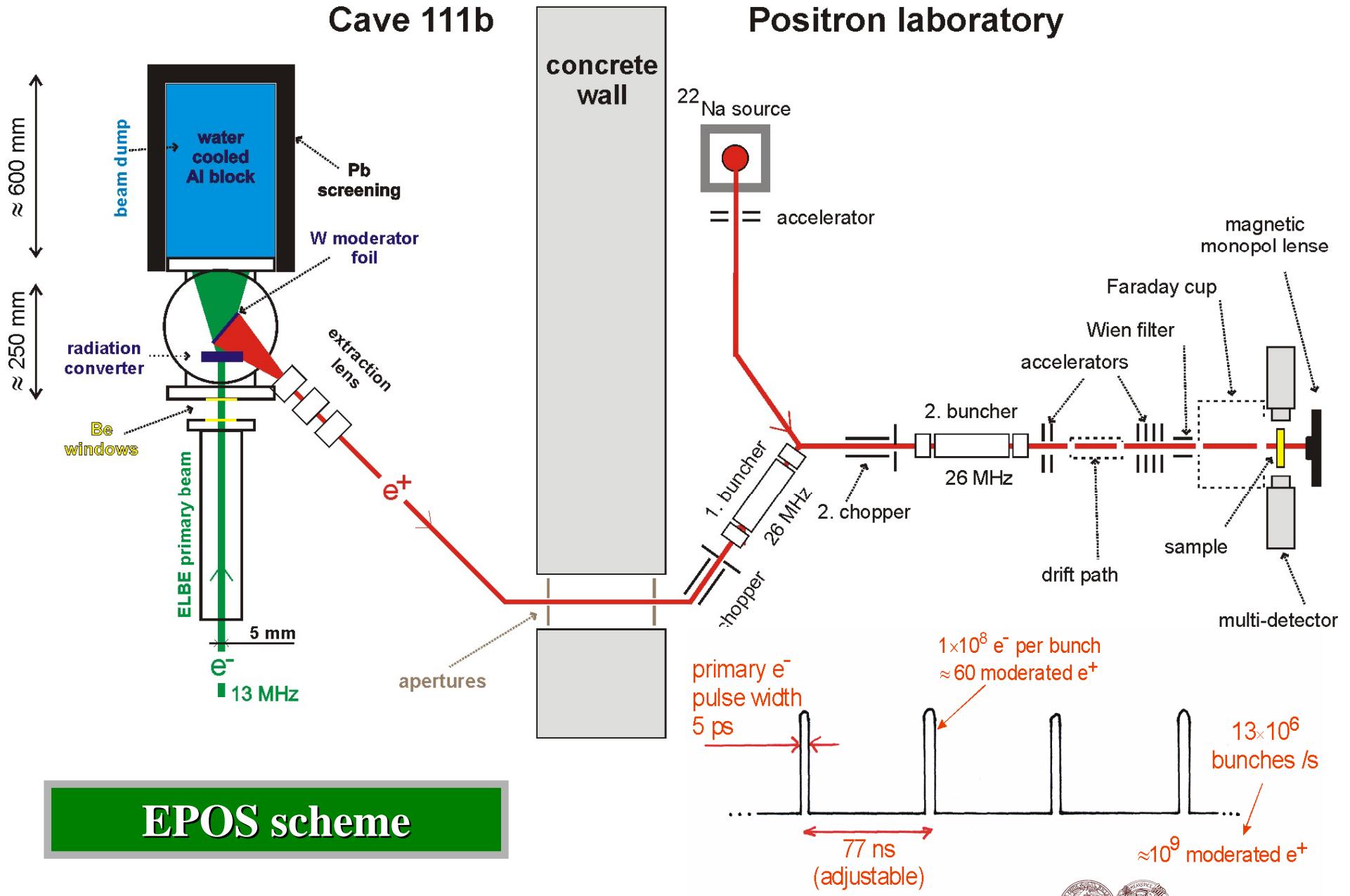
X-ray Lab

Positron Lab

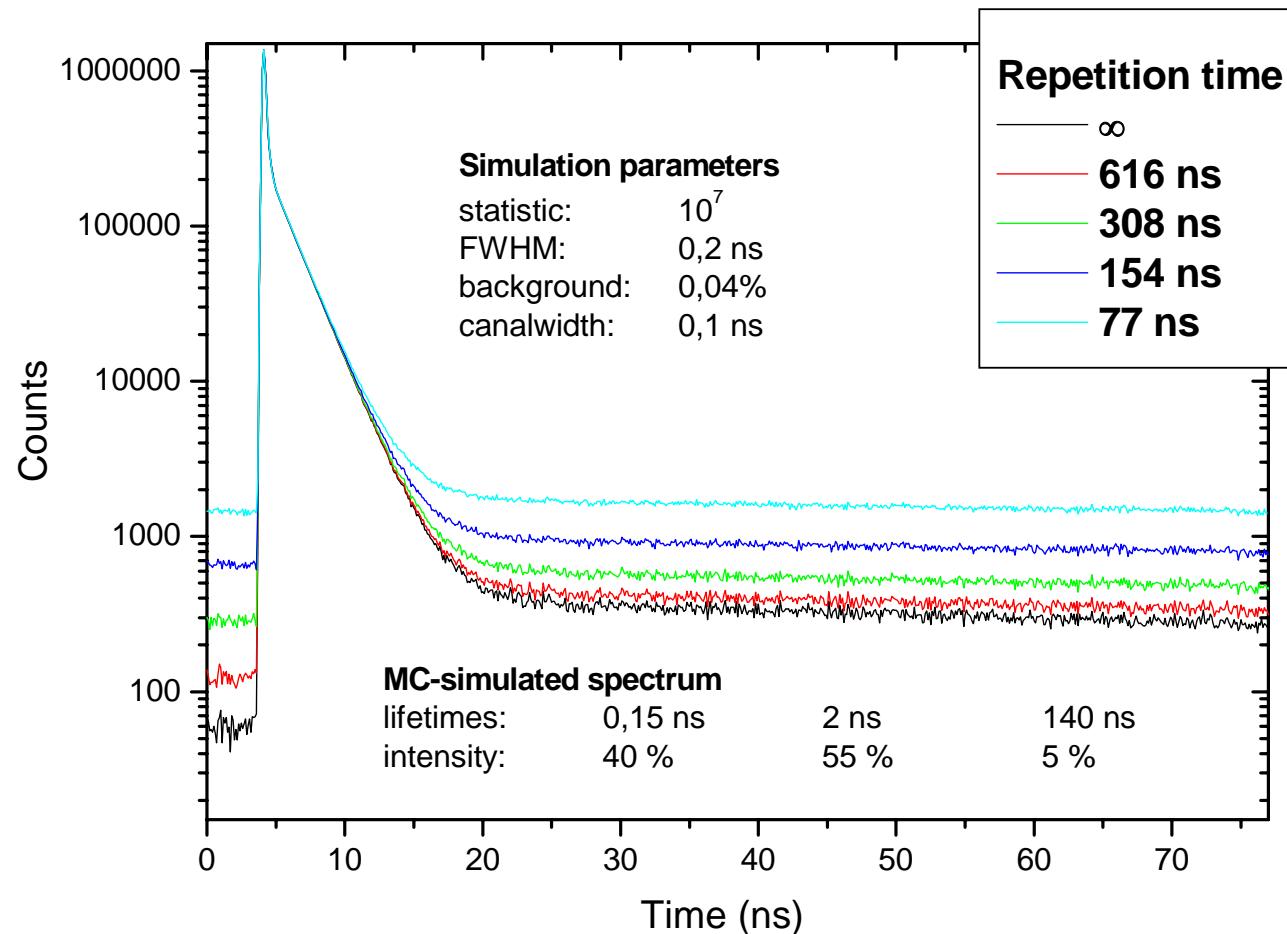
concrete screening of Cave 111b
(location of e^+ converter)







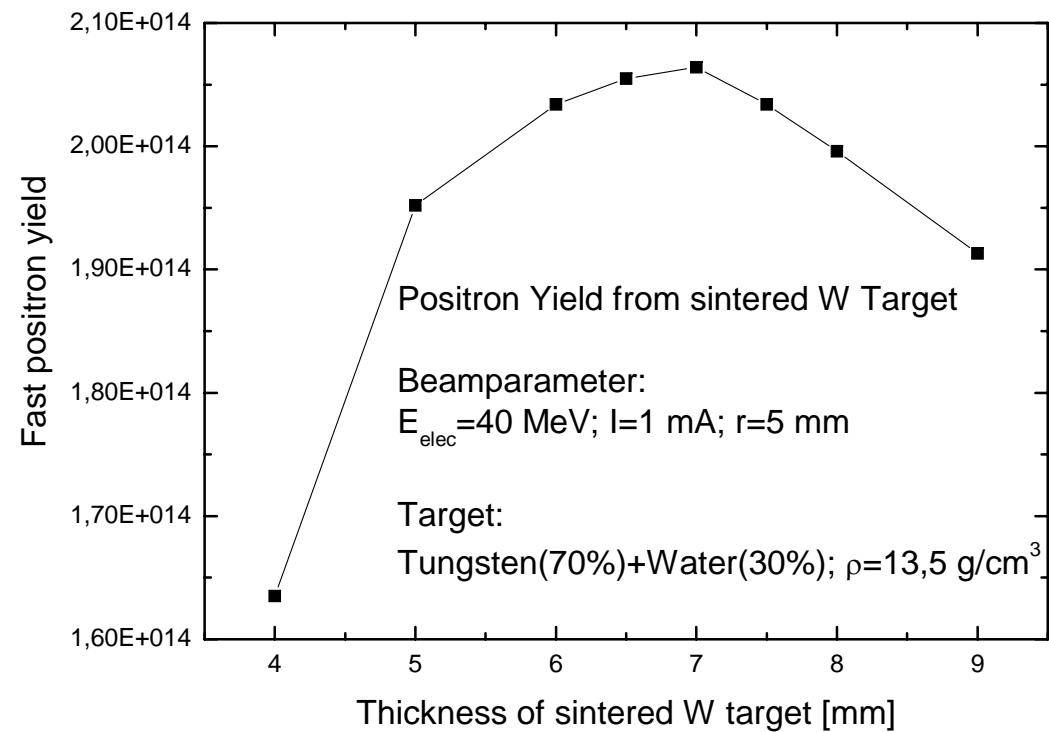
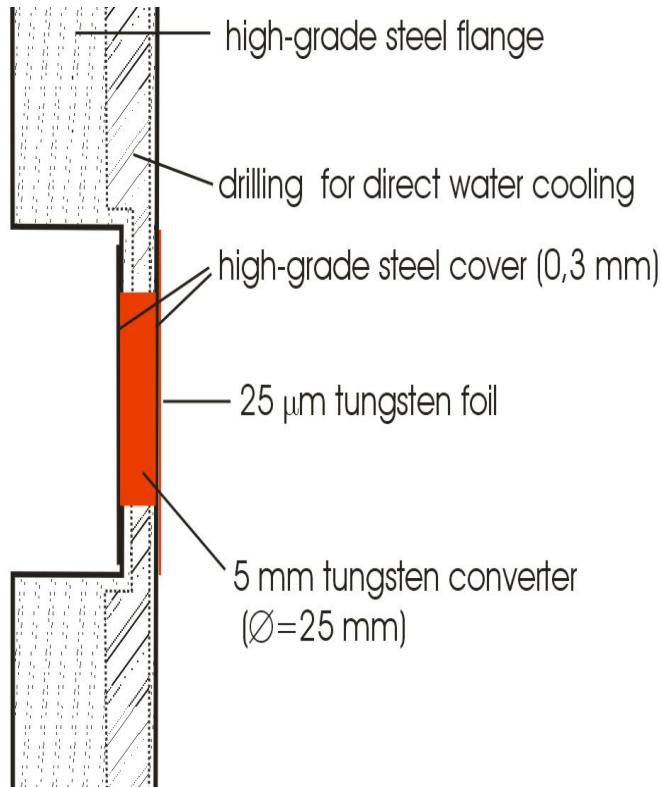
Second timing mode needed for long lifetimes (porous material)



Result of Fit:

Repetition time	Lifetime	Intensity
616 ns	141 ns	5,1 %
308 ns	124 ns	4,9 %
154 ns	75 ns	3,3 %
77 ns	35 ns	1,7 %

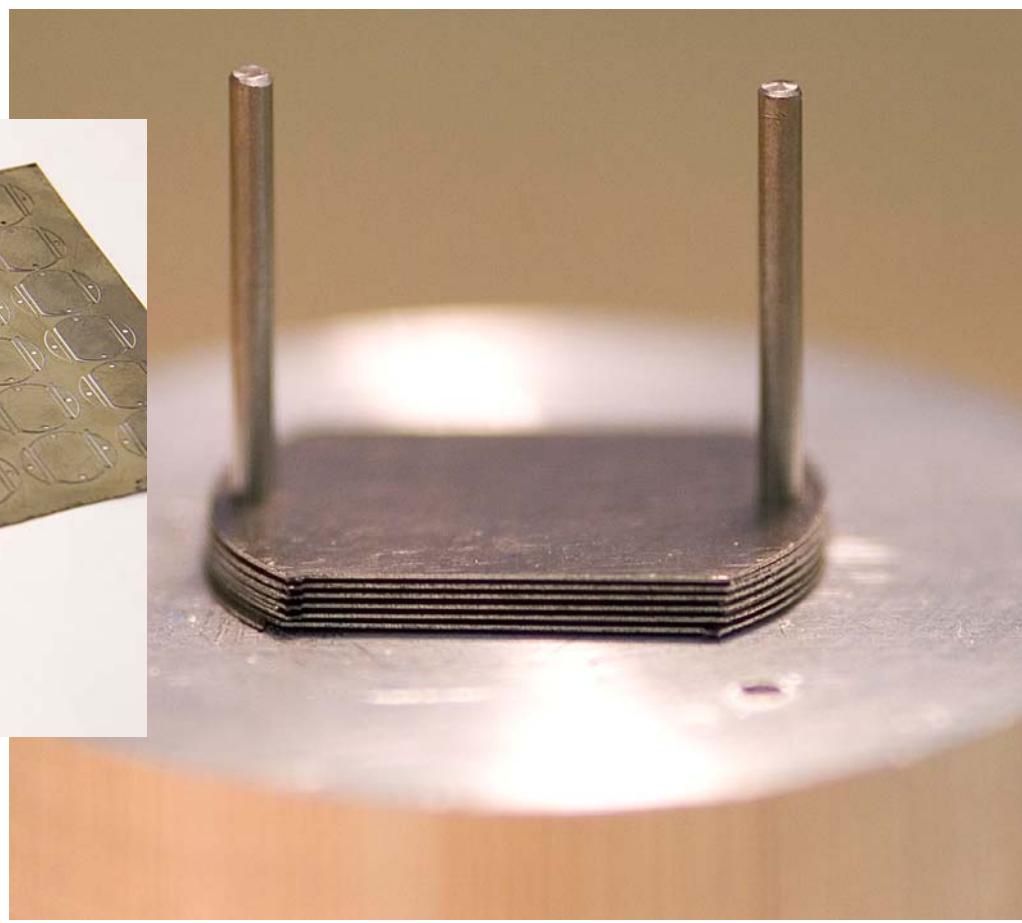
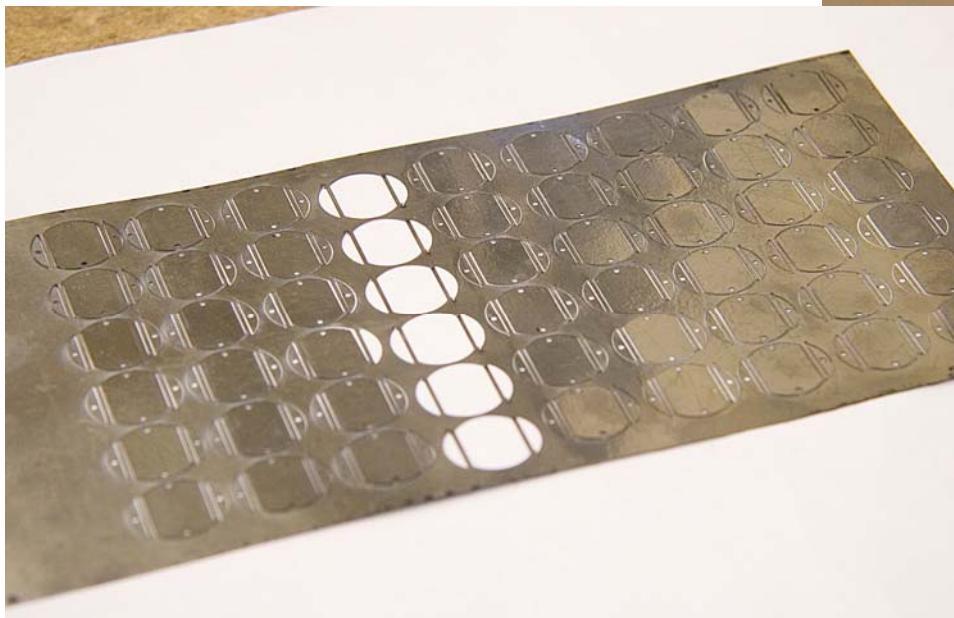
Converter



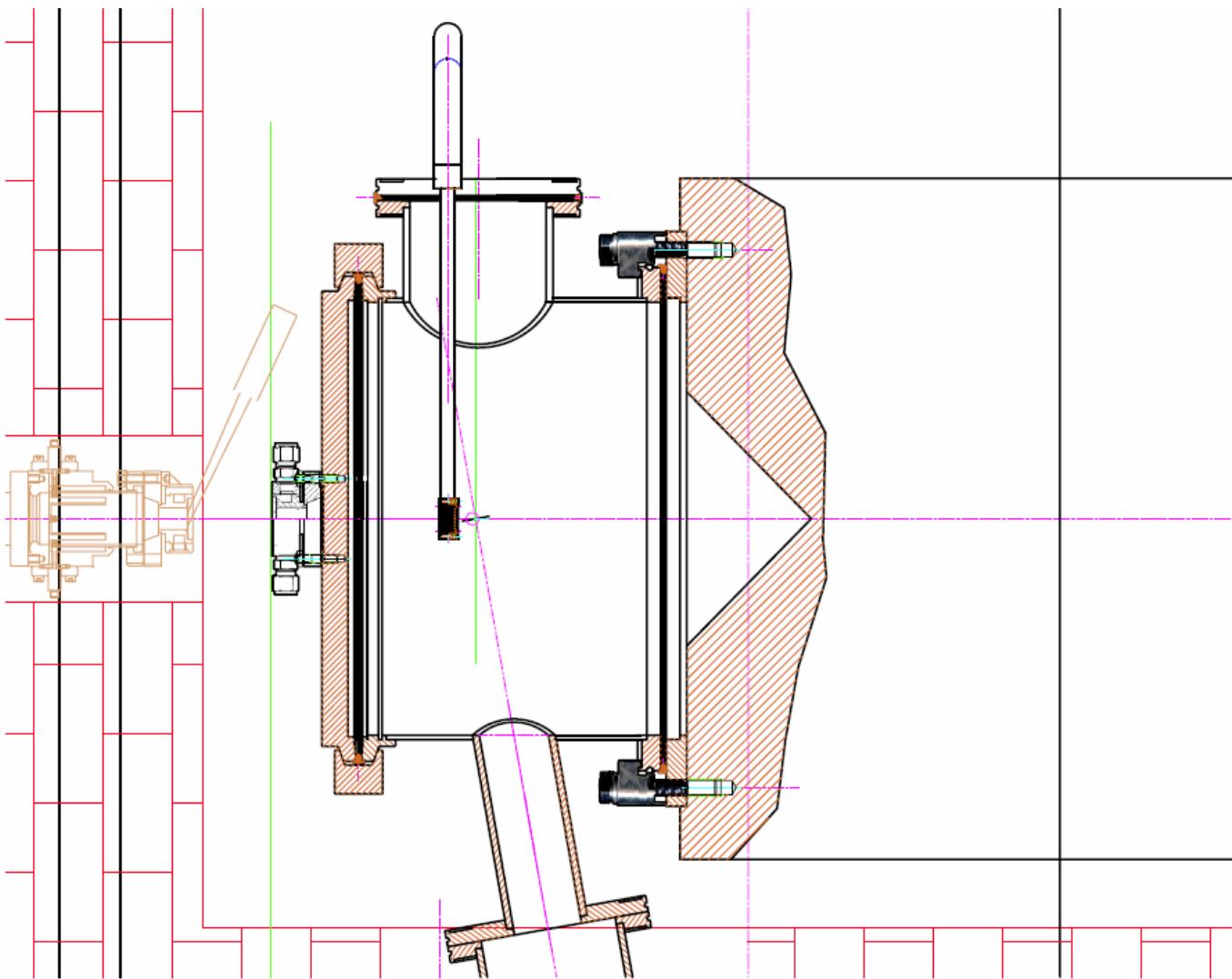
MCNP-Simulationen A. Rogov und K. Noack (FZR)

Directly water-cooled Electron-Positron Converter

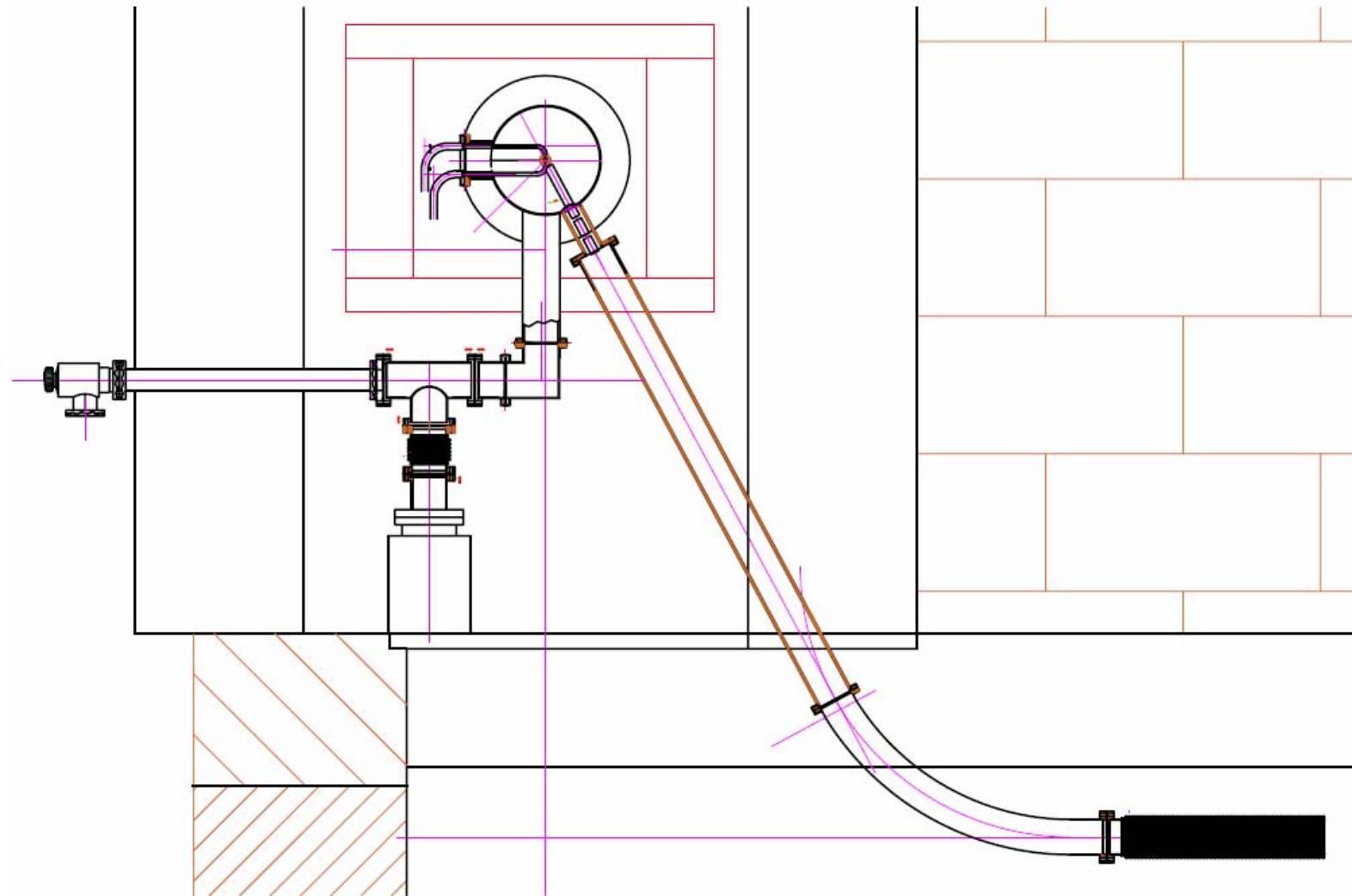
- first attempt: porous W (30 % porosity) -> too low water flux at 10 bar
- stack of 50 pieces W-foils 0,1 mm separated by 0,1 mm -> 13,5 l water at 1,5 bar
- foils cut by IR-laser in our workshop

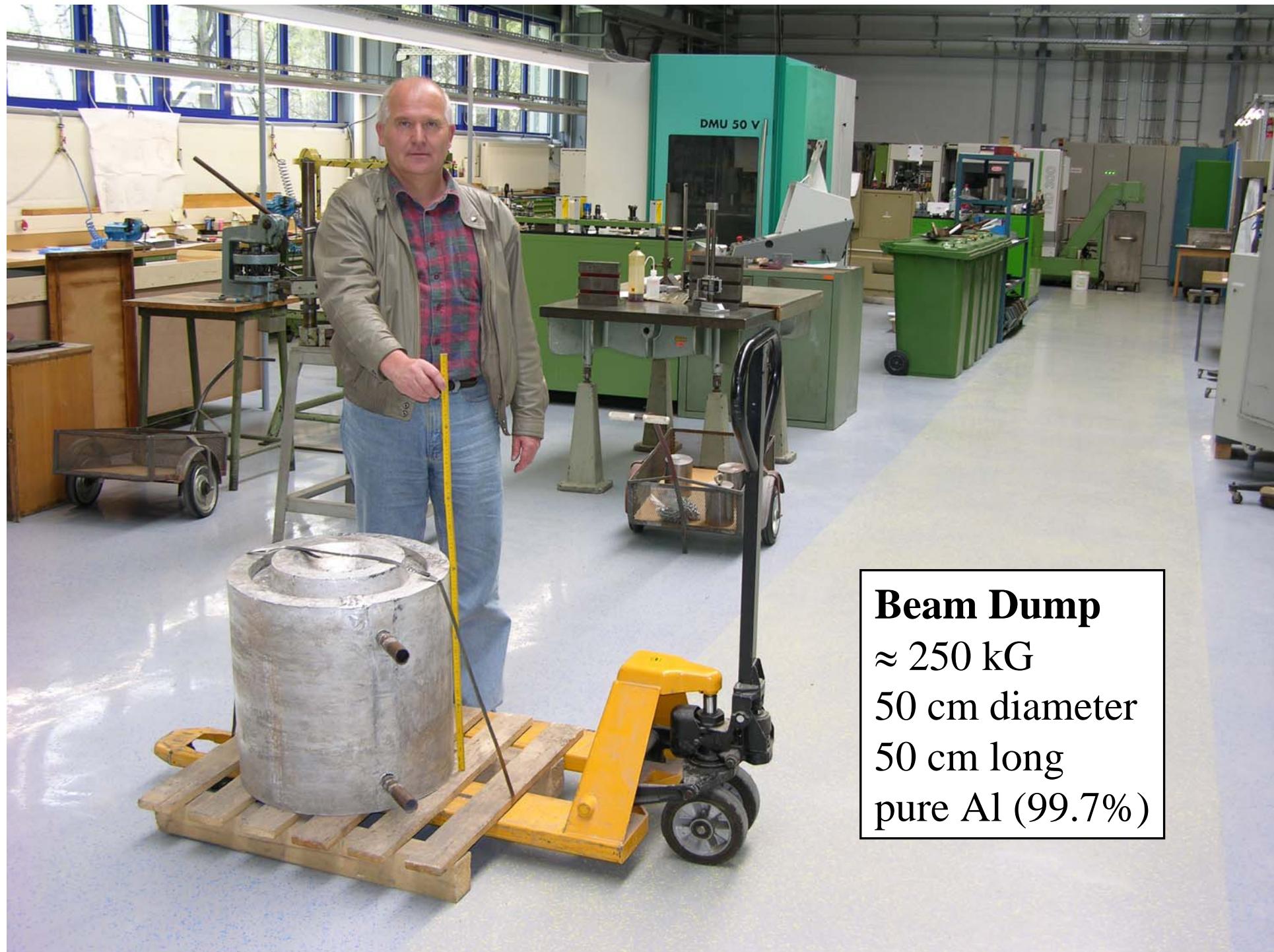


Converter Chamber



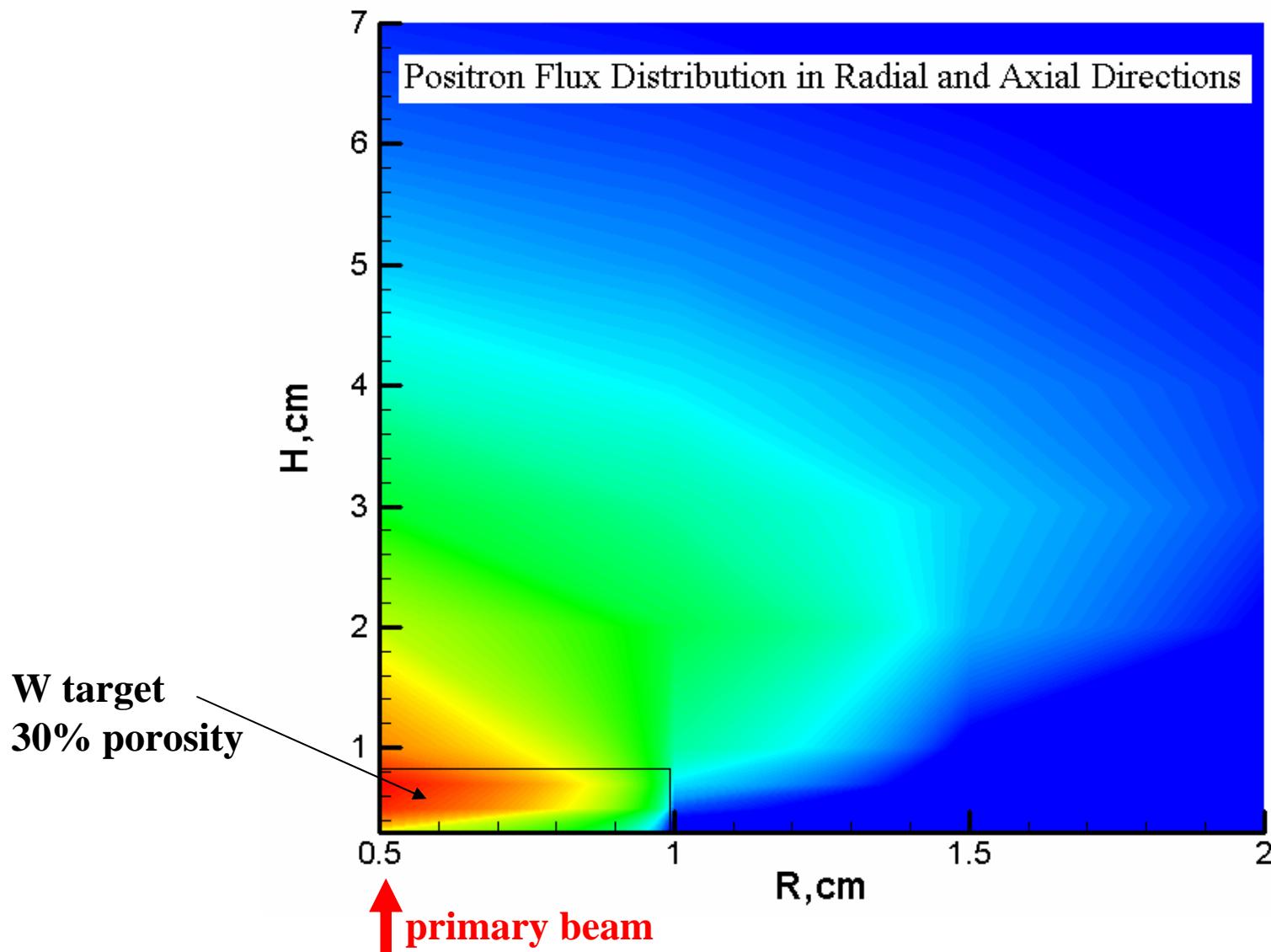
Converter Chamber





Beam Dump
 ≈ 250 kG
50 cm diameter
50 cm long
pure Al (99.7%)

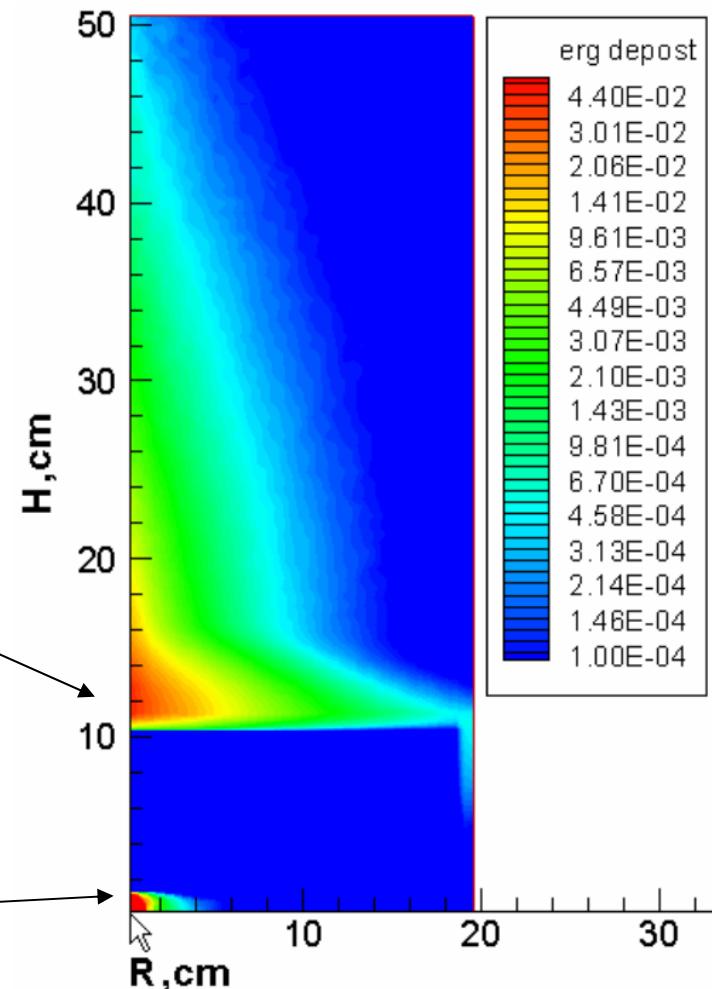
Simulation of Positron distribution



Simulation of Energy deposition

**Al beam dump 21 kW
(made of 5N-purity)**

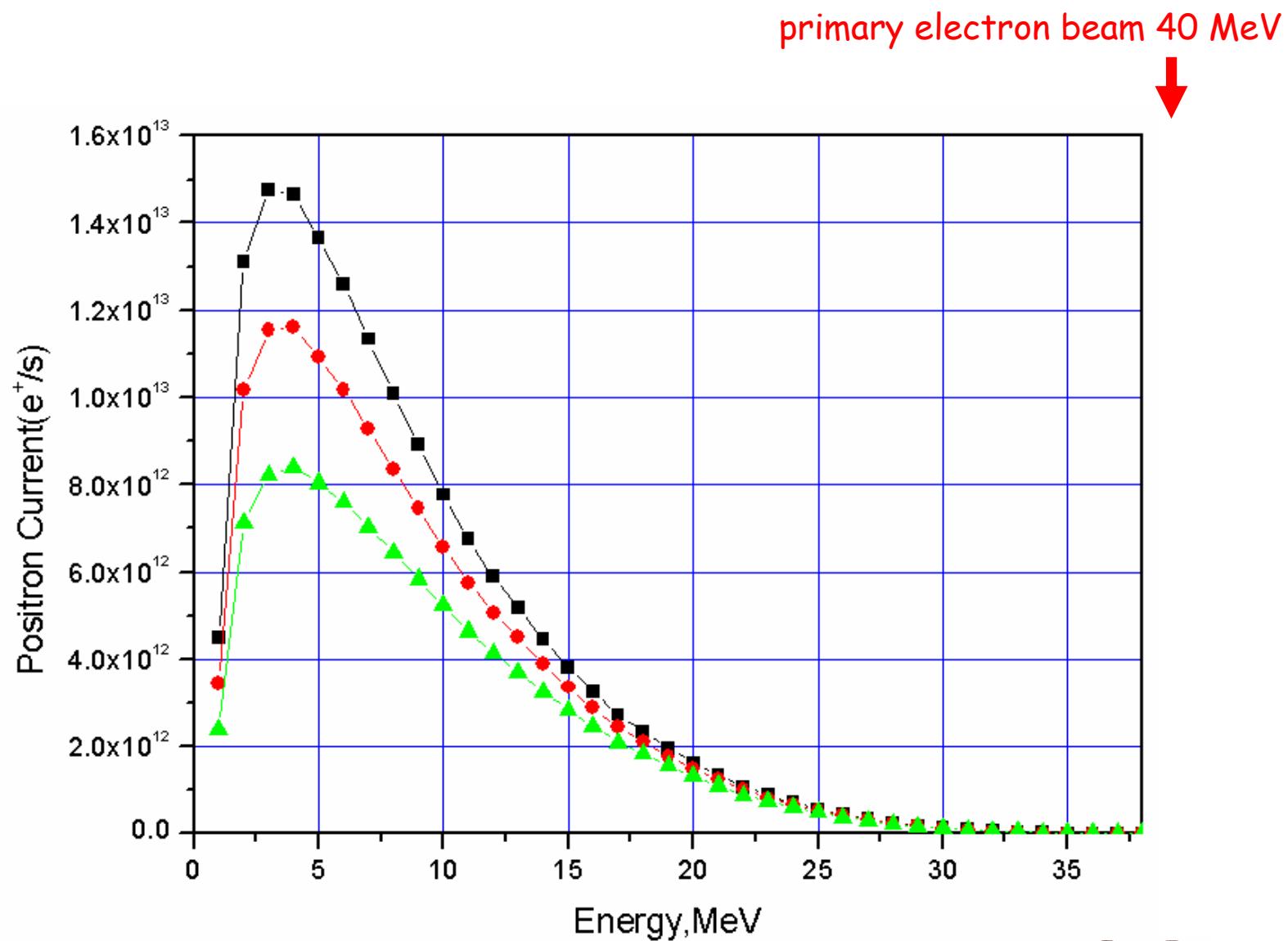
**W target
14 kW**



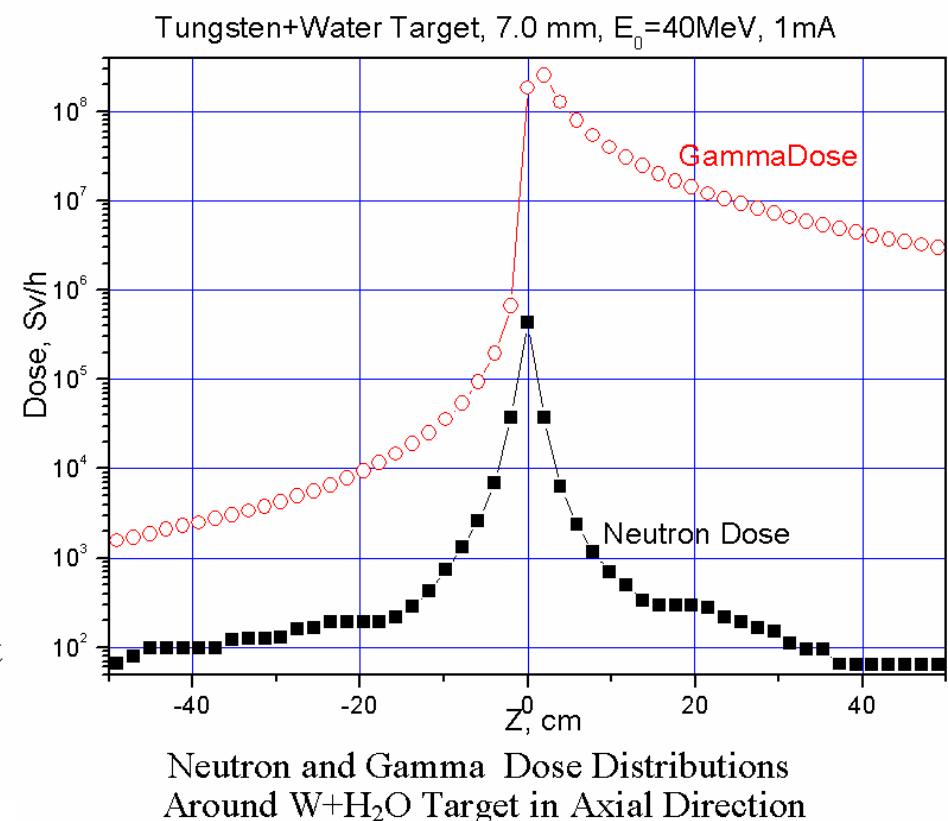
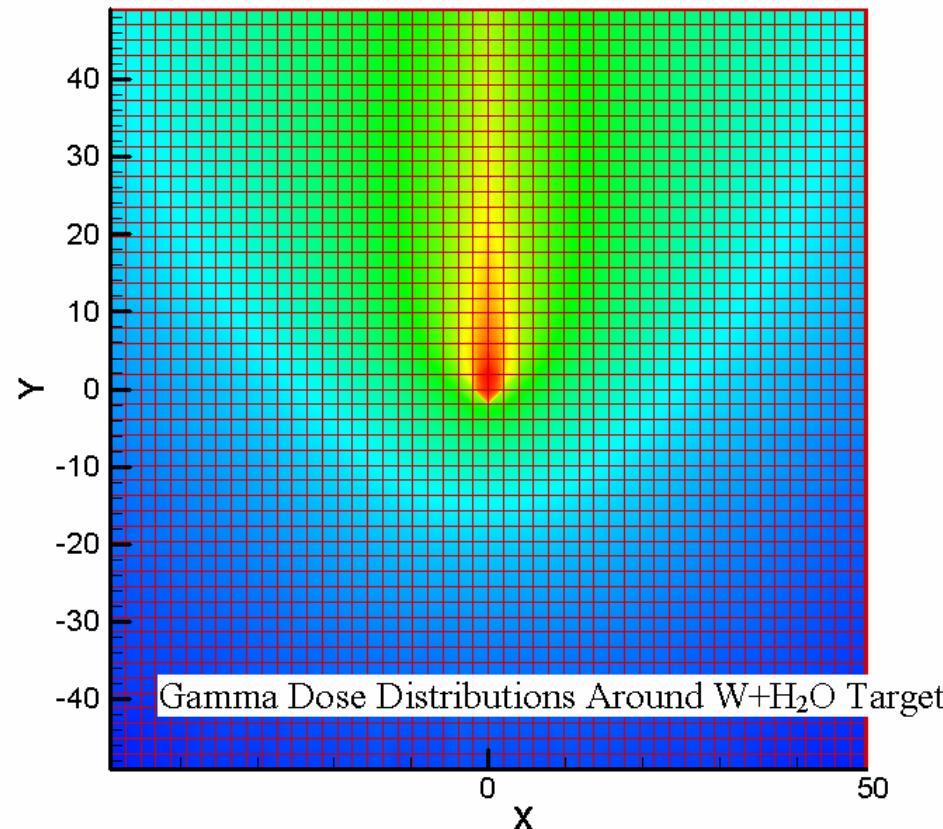
EPOS Density Energy Deposition (in MeV/cm³) for Distance = 10cm

↑ primary beam

Simulation of Positron Energy Distribution



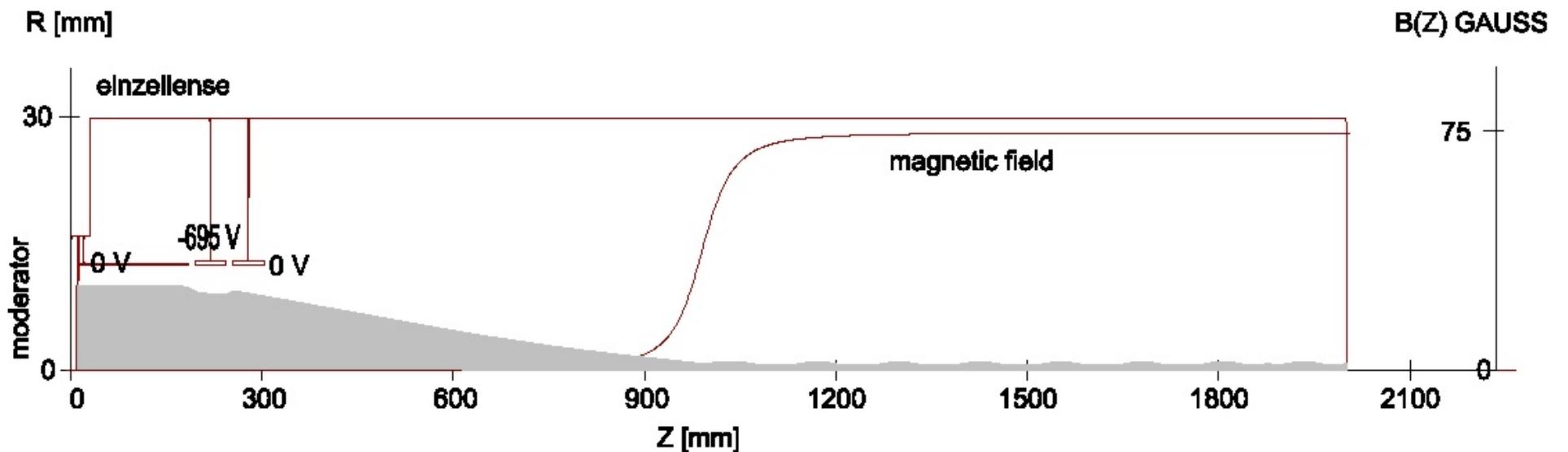
Simulation of expected γ and n dose



Screening by lead blocks, Polyethylene bricks and heavy concrete

Simulation of positron extraction

- simulation done by EGUN
- area of 20 mm diameter at moderator is used and squeezed to about 2 mm



Magnetic Beam Guidance

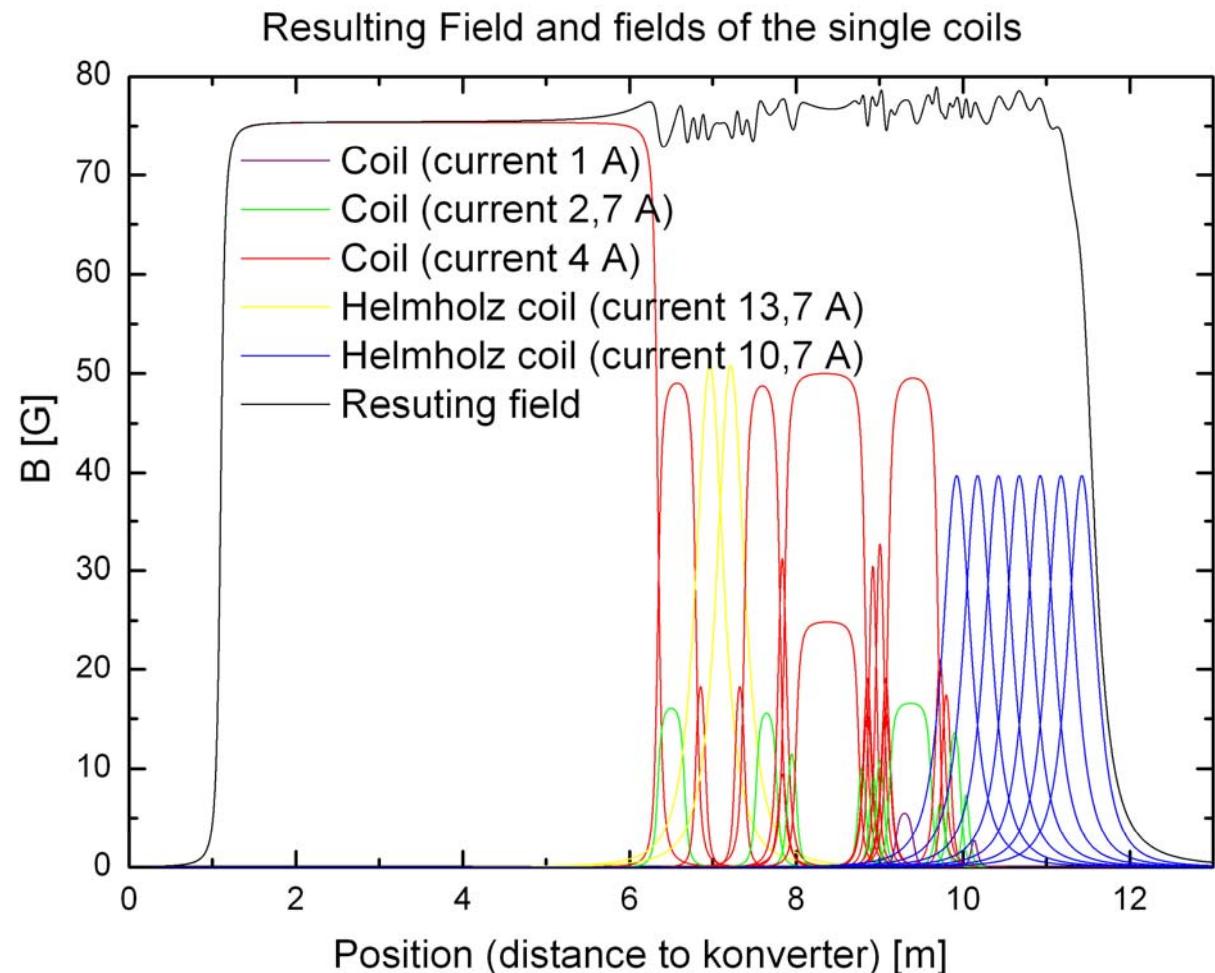
Magnetic field of 75 Gauss

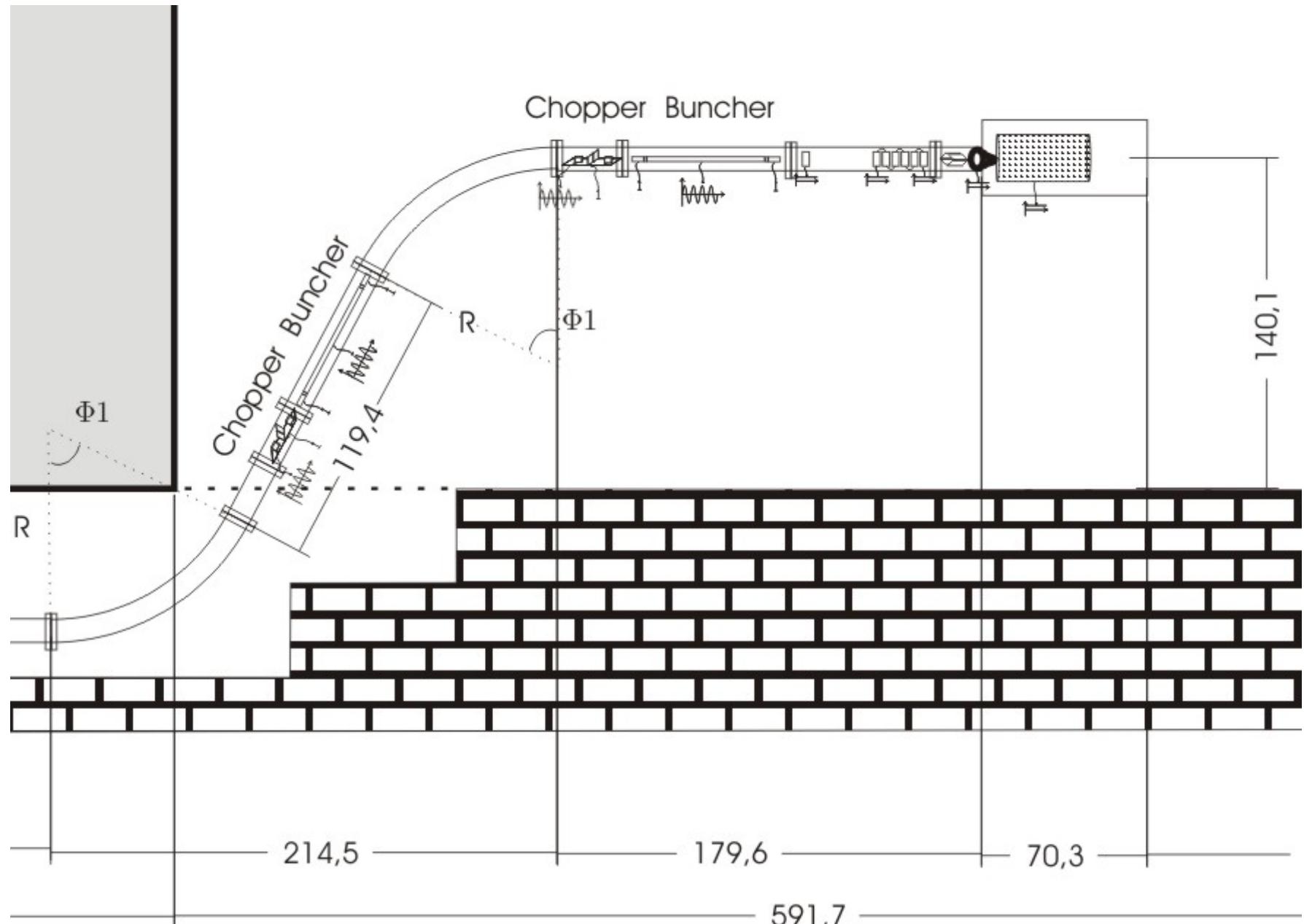
45 coils but only
5 different currents
5 Power supplies
2.7 kW Power together

→ maximum change 6 G
→ Gradient < 0,11 G/mm

Steering coils

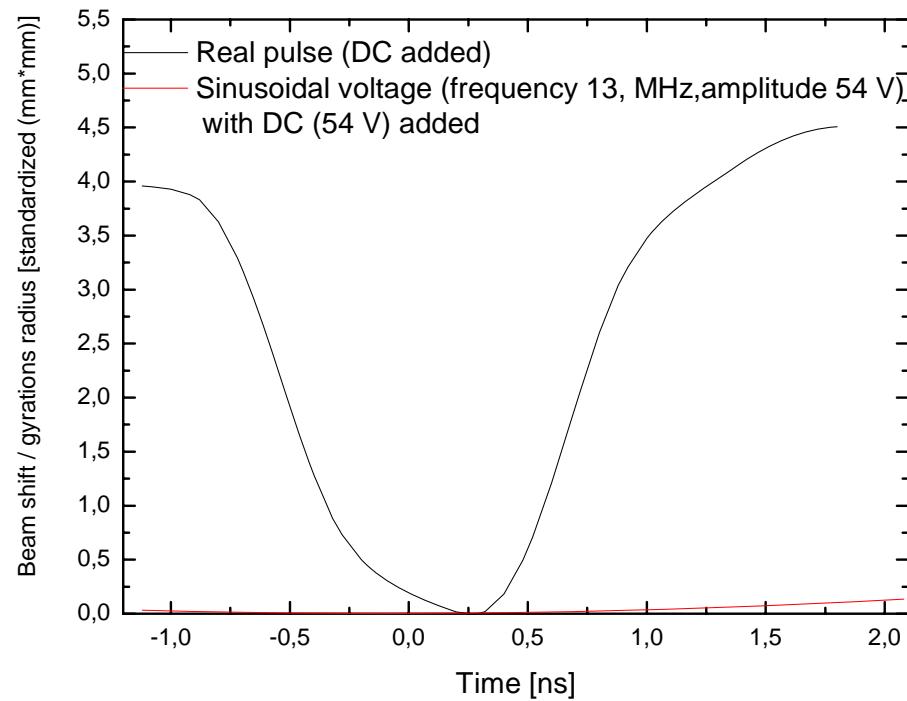
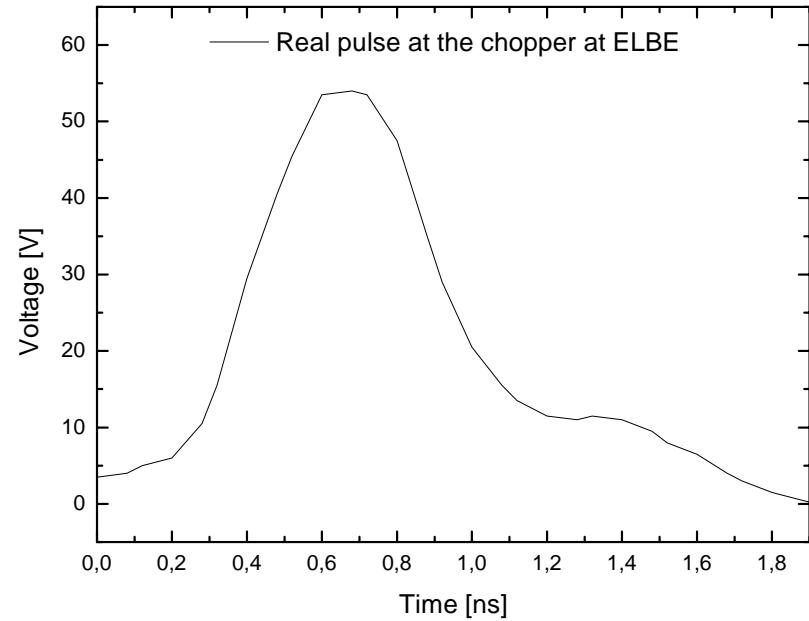
30 coils with different
(computer-driven) currents





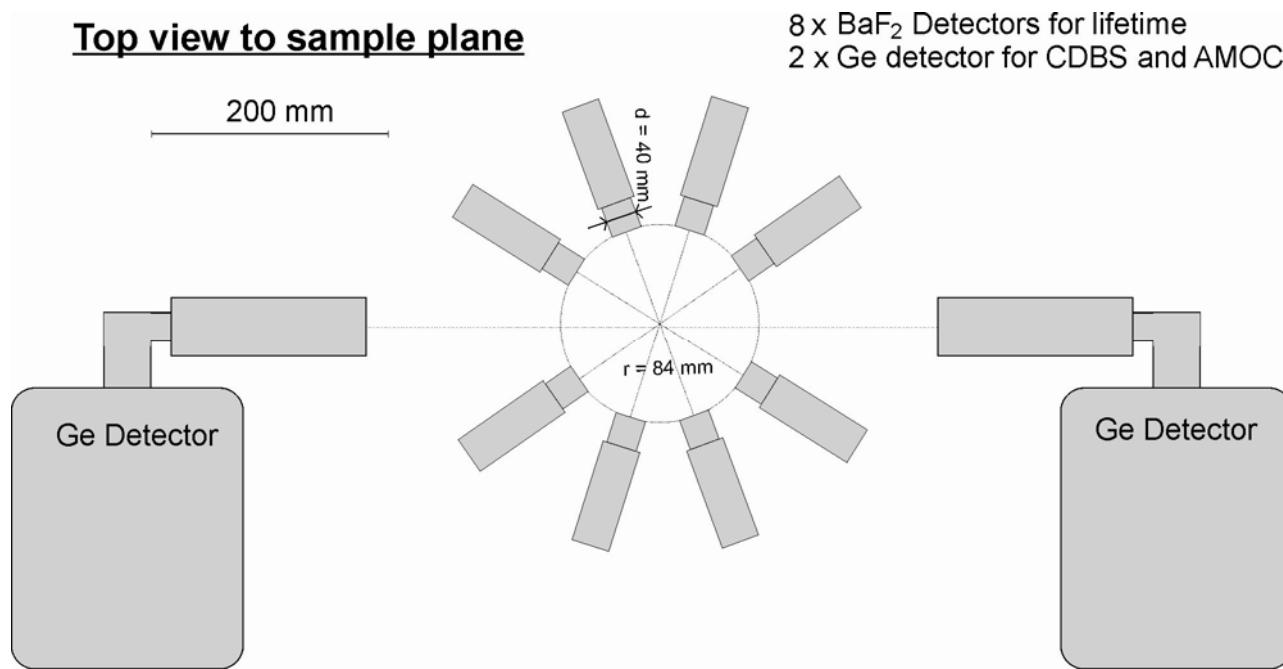
- Simulation of bunching by POSBUNCH
- C++ author: V. Bondarenko
- source code available on request

Chopper



Detector system

- **3 experiments:** lifetime spectroscopy (8 BaF₂ detectors); Doppler coincidence (2 Ge detectors), and AMOC (1 Ge and 1 BaF₂ detector)
- **digital detection system:**
 - lifetime: almost nothing to adjust; time scale exactly the same for all detectors; easy realization of coincidence
 - Doppler: better energy resolution and pile-up rejection expected
 - pulse-shape discrimination improves spectra quality



Time Schedule

	1. Year	2. Year	3. Year
Laboratory			
Simulation e ⁺ converter			
Simulation beam			
Converter chamber and vacuum system in tunnel			
Screening of converter chamber			
First chopper / buncher			
Test converter / beam transport			
Vacuum system completion			
Conventional source chamber			
2. Chopper / buncher			
Sample chamber			
Completion of beam electronics			
Test transport system			
Detector system and software			
Automation			
Software lifetime / Doppler spectra			
Optimization of time resolution			



EPOS - Applications

Variety of applications in all field of materials science:

- defect-depth profiles due to surface modifications and ion implantation
- tribology (mechanical damage of surfaces)
- polymer physics (pores; interdiffusion; ...)
- low-k materials (thin high porous layers)
- defects in semiconductors, ceramics and metals
- epitaxial layers (growth defects, misfit defects at interface, ...)
- fast kinetics (e.g. precipitation processes in Al alloys; defect annealing; diffusion; ...)
- radiation resistance (e.g. space materials)
- many more ...

